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# High Speed Infrared Emitting Diodes, 890 nm, Surface Emitter Technology



### **DESCRIPTION**

As part of the <u>SurfLight</u> portfolio, the VSMY5890 is an infrared, 890 nm emitting diode based on GaAlAs surface emitter chip technology with high radiant intensity, high optical power and high speed, in a low profile 0805 surface mount (SMD) package.

#### **FEATURES**

• Package type: surface-mount

• Package form: 0805

• Dimensions (L x W x H in mm): 2 x 1.25 x 0.8

Peak wavelength: λ<sub>p</sub> = 890 nm

· High speed

• Angle of half intensity:  $\varphi = \pm 60^{\circ}$ 

• 0805 standard surface-mountable package

• Floor life: 168 h, MSL 3, according to J-STD-020

• Lead (Pb)-free reflow soldering

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>



- Miniature light barrier
- · Optical switch
- IR point source

PRODUCT SUMMARY				
COMPONENT	$I_e$ (mW/sr) at $I_F$ = 100 mA	φ <b>(°)</b>	$\lambda_{\mathbf{p}}$ (nm)	t <sub>r</sub> (ns)
VSMY5890	13	± 60	890	7

#### Note

Test conditions see table "Basic Characteristics"

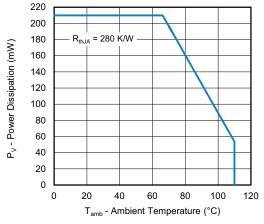
ORDERING INFORM	IATION		
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VSMY5890	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	0805

#### Note

· MOQ: minimum order quantity



ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.1, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	500	mA	
Power dissipation		P <sub>V</sub>	210	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +110	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +110	°C	
Soldering temperature	According to Fig. 7, J-STD-020	T <sub>sd</sub>	260	°C	
Thermal resistance junction-to-ambient	EIA / JESD51	R <sub>thJA</sub>	280	K/W	





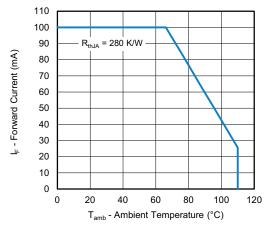


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$V_{F}$	-	1.8	2.1	V
Temperature coefficient of V <sub>F</sub>	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TK <sub>VF</sub>	-	-1.6	-	mV/K
Reverse current		I <sub>R</sub>	Not designed for reverse operation			μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $E = 0 \text{ mW/cm}^2$	CJ	-	30	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	10	13	18	mW/sr
Temperature coefficient of radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TΚφ <sub>e</sub>	-	-0.2	-	%/K
Angle of half intensity		φ	-	± 60	-	0
Peak wavelength	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$\lambda_{p}$	-	890	-	nm
Spectral bandwidth	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	Δλ	-	40	-	nm
Temperature coefficient of λ <sub>p</sub>	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$TK_{\lambdap}$	-	0.25	-	nm/K
Rise time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>r</sub>	-	8	-	ns
Fall time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>f</sub>	-	8	-	ns

## BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

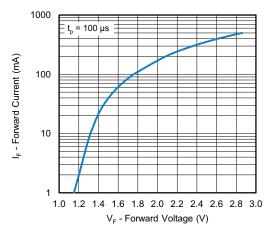
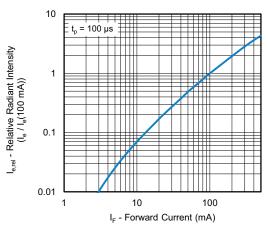


Fig. 3 - Forward Current vs. Forward Voltage



**REFLOW SOLDER PROFILE** 

Fig. 4 - Relative Radiant Intensity vs. Forward Current

#### 300 Max. 260 °C 255 250 240 200 remperature (°C) Max. 30 s 150 Max. 120 s Max. 100 s 100 Max. ramp down 6 °C/s 50 Max. ramp up 3 °C/s 0 50 100 200 250 300 150 19841 Time (s)

Fig. 7 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

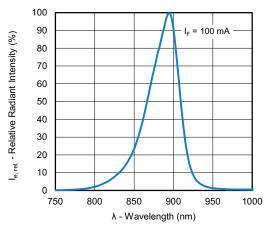


Fig. 5 - Relative Radiant Power vs. Wavelength

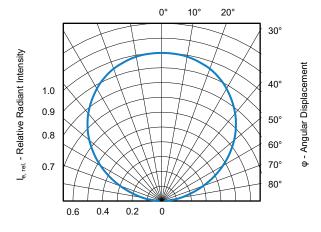


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

## **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

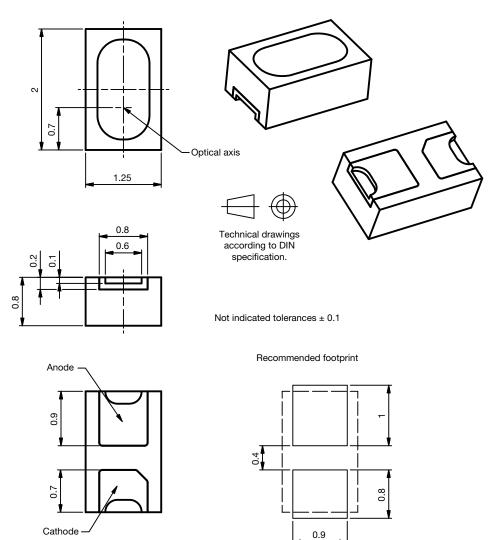
Floor life: 168 h

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

## DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.

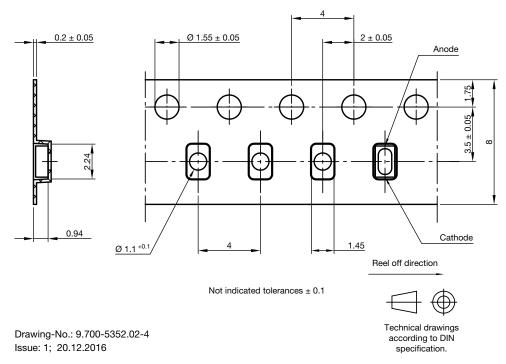
## **PACKAGE DIMENSIONS** in millimeters



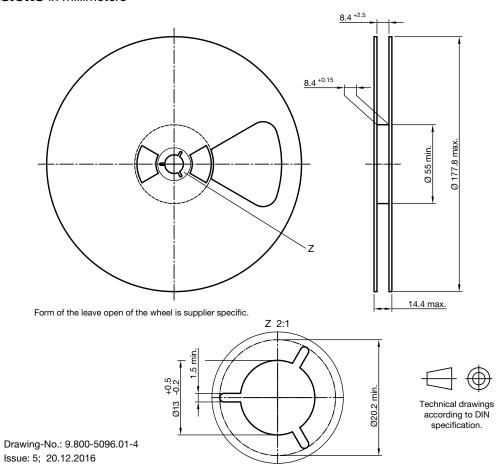
Drawing- No.: 6.550-5352.01-4

Issue: 1; 20.12.2016

### **BLISTER TAPE DIMENSIONS** in millimeters



### **REEL DIMENSIONS** in millimeters





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